

*Sub C1*  
7. (amended) A device according to any one of Claims 1, wherein the substrate comprises polymer material.

*q2*  
8. (amended) A device according to any one of Claims 1, wherein the areas of weakness extend as lines of weakness between the areas of the substrate carrying the semiconductor devices.

*Sub C1*  
9. (amended) A device according to any one of Claims 1, wherein the discrete areas of the substrate carrying the semiconductor devices are thicker than the remaining areas of substrate.

*Sub C2*  
10. (amended) A device according to claim 1, wherein the semiconductor devices each comprise a semiconductor film formed into an island.

*Sub C3*  
11. (amended) A device according to claim 1, wherein the semiconductor devices comprises thin film transistors.

*Sub C8*  
12. (amended) A device according to claim 1, wherein the device comprises an active matrix display devices having an array of display pixels and in which each semiconductor device is connected to a respective pixel electrode carried on the substrate.